SILICON POWER TRANSISTOR 2SA1744

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1744 is a power transistor developed for high-speed switching and features a high hFE at Low $V_{CE(sat)}$. This transistor is ideal for use as a driver in DC/DC converters and actuators.

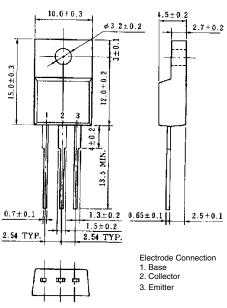
In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

FEATURES

NEC

- High hFE and low VCE(sat): hFE \geq 100 (VCE = -2 V, IC = -3 A) VCE(sat) \leq 0.3 V (IC = -8 A, IB = -0.4 A)
- Full-mold package that does not require an insulating board or bushing

PACKAGE DRAWING (UNIT: mm)



ISOLATED TO-220(MP 45F)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	-100	V
Collector to emitter voltage	VCEO	-60	V
Emitter to base voltage	Vebo	-7.0	V
Collector current (DC)	IC(DC)	-15	А
Collector current (pulse)	I _{C(pulse)} *	-30	А
Base current (DC)	B(DC)	-7.5	А
Total power dissipation	P⊤ (Tc = 25°C)	30	W
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

* PW \leq 300 μ s, duty cycle \leq 10%

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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

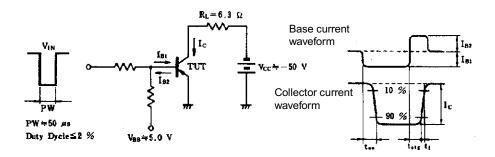
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = −8.0 A, I _B = −0.8 A, L = 1 mH	-60			V
Collector to emitter voltage	VCEX(SUS)	Ic = -8.0 A, I _{B1} = -I _{B2} = -0.8 A, V _{BE(OFF)} = 1.5 V, L = 180 μ H, clamped	-60			V
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, \text{ I}_{E} = 0$			-10	μA
Collector cutoff current	ICER	$V_{CE} = -60 \text{ V}, \text{ R}_{BE} = 50 \Omega, \text{ T}_{A} = 125^{\circ}\text{C}$			-1.0	mA
Collector cutoff current	ICEX1	$V_{\text{CE}} = -60 \text{ V}, \text{ V}_{\text{BE(OFF)}} = 1.5 \text{ V}$			-10	μA
Collector cutoff current	ICEX2	$\label{eq:Vce} \begin{split} V_{CE} &= -60 \ V, \ V_{BE(OFF)} = 1.5 \ V, \\ T_A &= 125^{\circ}C \end{split}$			-1.0	mA
Emitter cutoff current	Іево	V _{EB} = -5.0 V, Ic = 0			-10	μA
DC current gain	hfe1*	Vce = -2.0 V, Ic = -1.5 A	100			
DC current gain	hfe2*	Vce = -2.0 V, Ic = -3.0 A	100		400	
DC current gain	hfe3*	Vce = -2.0 V, Ic = -8.0 A	60			
Collector saturation voltage	V _{CE(sat)1} *	Ic = -8.0 A, I _B = -0.4 A			-0.3	V
Collector saturation voltage	VCE(sat)2*	Ic = -12 A, Iв = -0.6 A			-0.5	V
Base saturation voltage	V _{BE(sat)1} *	$I_{C} = -8.0 \text{ A}, I_{B} = -0.4 \text{ A}$			-1.2	V
Base saturation voltage	VBE(sat)2*	Ic = -12 A, Iв = -0.6 A			-1.5	V
Collector capacitance	Cob	$V_{CB} = -10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1.0 \text{ MHz}$		300		pF
Gain bandwidth product	f⊤	Vce = -10 V, Ic = -1.5 A		80		MHz
Turn-on time	ton	Ic = -8.0 A, R _L = 6.3 Ω,			0.3	μs
Storage time	tstg	I _{B1} = −I _{B2} = −0.4 A, Vcc ≅ −50 V Refer to the test circuit.			1.5	μs
Fall time	tr				0.3	μs

* Pulse test PW \leq 350 μ s, duty cycle \leq 2%

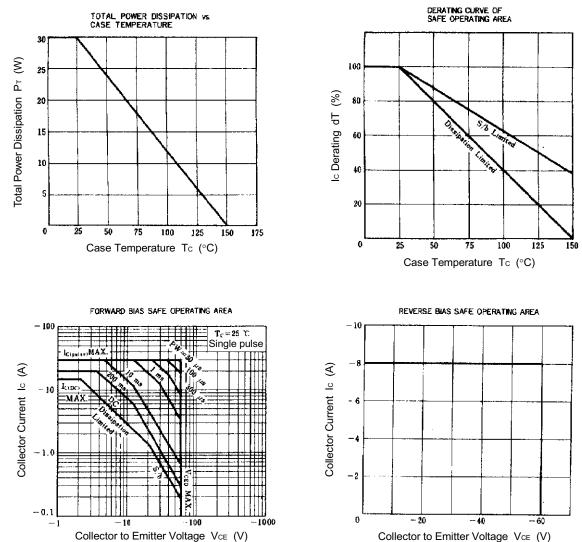
hfe CLASSIFICATION

Marking	М	L	к
hFE2	100 to 200	150 to 300	200 to 400

SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

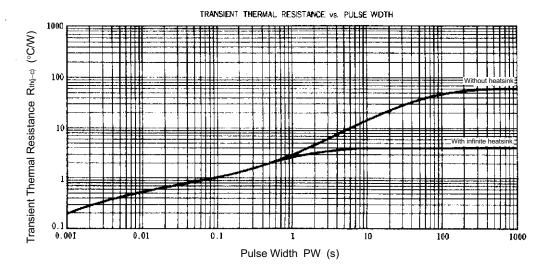


TYPICAL CHARACTERISTICS (TA = 25°C)

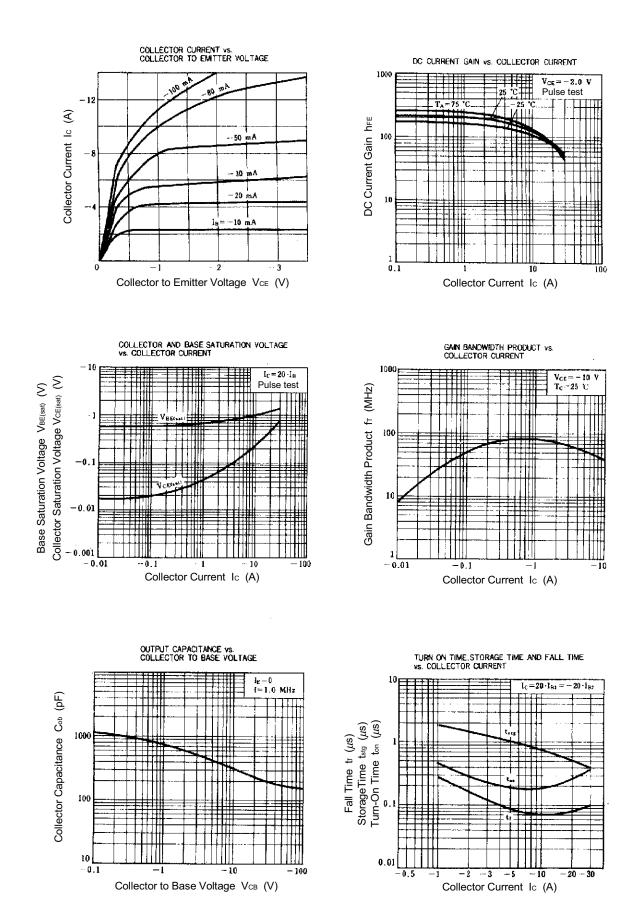


Collector to Emitter Voltage VCE (V)





Data Sheet D13160EJ1V0DS



[MEMO]

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